

# Single Line ESD Protection Diode **Description**

The SESDFBP05C ESD protection diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs.

#### Applications

- · Cellular phones handsets and Accessories
- PDA's
- MP3 players
- Digital cameras
- · Portable applications
- mobile telephone

#### Features

- Equivalent to 0402 package
- 120W peak pulse power
- Small package for use in portable electronics
- Standoff voltage : 5V
- Low leakage current
- RoHS compliant package

Complies with the following standards

IEC61000-4-2

Level 4 15 kV (air discharge)

8 kV(contact discharge)

MIL STD 883E - Method 3015-7 Class 3

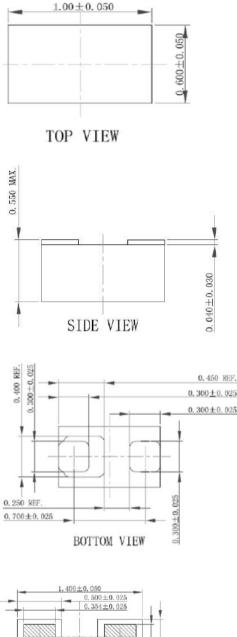
25 kV HBM (Human Body Model)

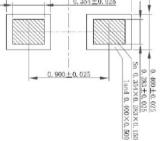
#### **Packing & Order Information**

3,000/Reel

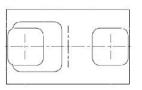


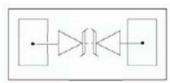






#### **Graphic symbol**







### Single Line ESD Protection Diode

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute ratings @25°C Unless Otherwise Specified					
Symbol	Parameter	Value	Unit		
	IEC 61000-4-2 (ESD) Contact	8	Kv		
$P_{PP}$	Peak Pulse Power	120	W		
Ipp	Peak Pulse Power	12	А		
$T_J, T_{STG}$	Junction and Storage Temperature Range	-55 to +150	°C		
T <sub>L</sub>	Lead Solder Temperature – Maximum (10 Second Duration)	260	°C		

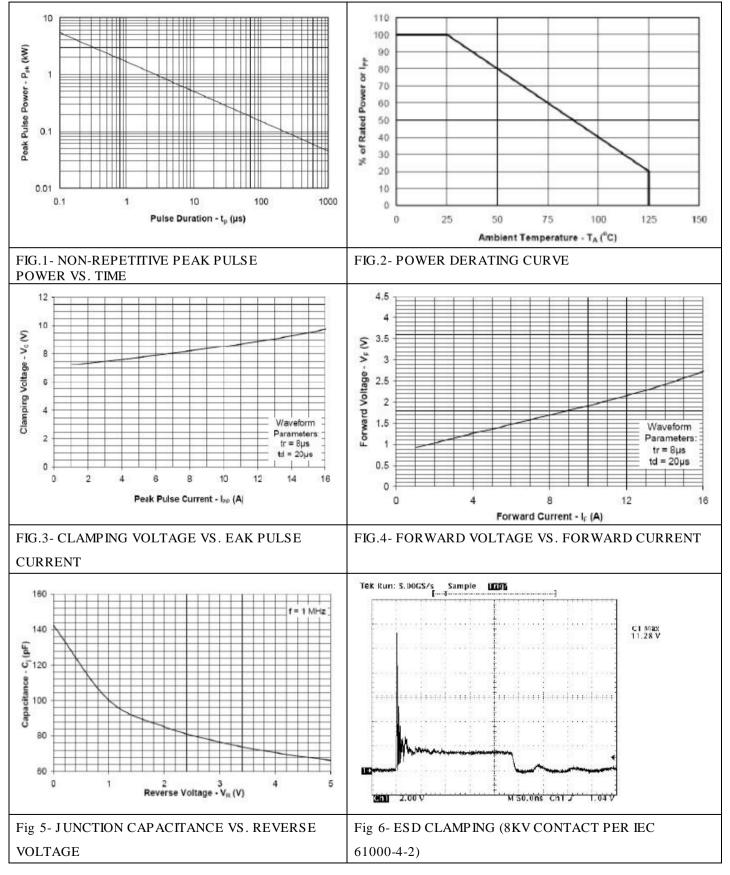
Electrical Characteristics							
		VBR		In	VRWM	IR	С
Part Numbers	Min.	Typ.	Max.				ТҮР
	V	V	V	mA	V	uA	PF
SESDFBP05C	6.1	6.6	7.2	1	5	1	10

Symbol	Parameter	1 88		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current			
Vc	Clamping Voltage @ I <sub>PP</sub>			
V <sub>RWM</sub>	Working Peak Reverse Voltage	$V_{BR}V_{RWM}$ $I_R$ $I_T$ $V$		
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>	IT IR VRWM VBRVC		
Ι <sub>Τ</sub>	Test Current			
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>	  PP		



### Single Line ESD Protection Diode

Typical Device Characteristics





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